# Power Diode - Fast Recovery multicomp





#### Features:

- Low forward voltage drop
- High current capability
- High reliability
- · High surge current capability

### **Mechanical specifications:**

Cases	: Moulded plastic
Lead	: Axial leads, solderable per MIL-STD-202, Method 208 guaranteed.
Polarity	: Colour band denotes cathode end.
High temperature soldering guaranteed	: 260°C/10 seconds/0.375", (9.5mm) lead lengths at 5lbs., (2.3kg) tension.

### **Maximum Ratings and Electrical Characteristics**

Rating at 25°C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Type Number	Symbol	FR107	Unit
Maximum recurrent peak reverse voltage	Vrrm	1,000	
Maximum RMS voltage	VRMS	700	V
Maximum DC blocking voltage	VDC	1,000	
Maximum average forward rectified current 0.375" (9.5mm) lead length at TA = 55°C	I(AV)	1	_
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	Ігѕм	30	A
Maximum instantaneous forward voltage at 1.0A	VF	1.2	V
Maximum DC reverse current at TA = 25°C at rated DC blocking voltage at TA = 100°C	lr	5 100	uA
Maximum reverse recovery time (Note 1)	Trr	500	ns
Typical junction capacitance (Note 2)	Cj	10	pF
Typical thermal resistance (Note 3)	Rθja Rθjc	65 8	°C/W
Operating temperature range	TJ	65 to ±150	°C
Storage temperature range	Тѕтс	-65 to +150	

#### Notes:

- 1. Reverse recovery test conditions:  $I_F = 0.5A$ ,  $I_R = 1A$ ,  $I_{RR} = 0.25A$
- 2. Measured at 1MHz and applied reverse voltage of 4V DC
- 3. Mount on Cu-Pad Size 5mm × 5mm on PCB



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### **Ratings and Characteristic Curves**

Figure 1 Maximum Forward Current Derating Curve

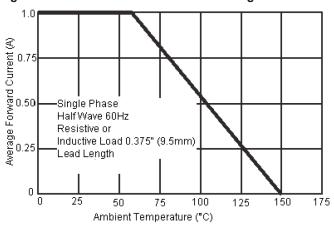


Figure 2 Maximum Non-Repetitive Forward Surge Current

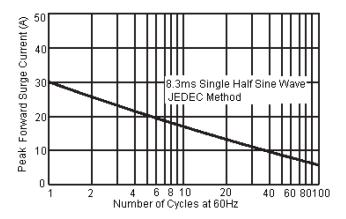
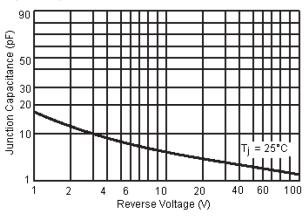
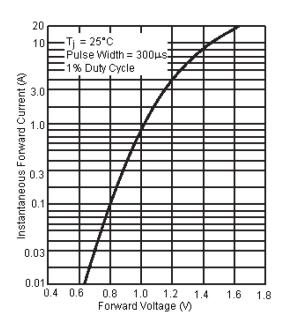


Figure 4 Typical Junction Capacitance



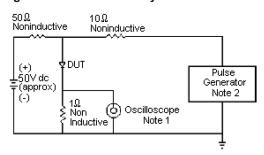
**Figure 3 Typical Forward Characteristics** 



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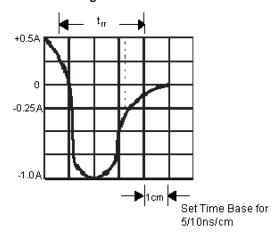


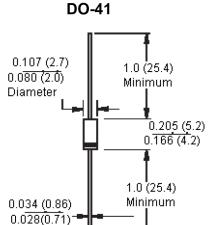
Figure 5 Reverse Recovery Time Characteristic and Test Circuit Diagram



Note: 1. Rise Time = 7nS Max. Input Impedance =  $1M\Omega$ , 22pF

> 2. Rise Time = 10nS Max. Source Impedance =  $50\Omega$





Dimensions: Inches (Millimetres)

Diameter

#### **Part Number Table**

Description	Length	Diameter	Part Number
Power Diodes - Fast Recovery	5.2mm	2.7mm	FR107

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